

STTH60L04W

Ultrafast high voltage rectifier

Datasheet - production data

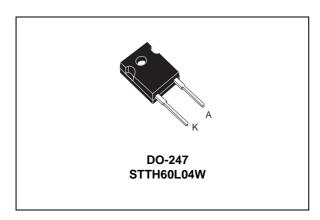


Table 1. Device summary

Symbol	Value
I _{F(AV)}	60 A
V _{RRM}	400 V
T _j (max)	175 °C
V _F (typ)	0.83 V
t _{rr} (max)	50 ns
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Features

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses

Description

The STTH60L04W uses ST 400 V technology and is specially suited for use in switching power supplies, welding equipment, and industrial applications, as an output rectification diode.

Characteristics STTH60L04W

Characteristics

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Paran	Value	Unit		
V_{RRM}	Repetitive peak reverse voltage	400	V		
I _{F(RMS)}	Forward rms current	90	Α		
I _{F(AV)}	Average forward current $T_c = 90 ^{\circ}\text{C}, \delta = 0.5$ Per diode			60	Α
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$			600	А
T _{stg}	Storage temperature range	-55 to + 175	°C		
Tj	Maximum operating junction temp	175	ů		

Table 3. Thermal resistance

Symbol	F	Parameter		Value (max)	Unit
R _{th(j-c)}	Junction to case		40	0.70	°C/W

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage	T _j = 25 °C	$V_R = V_{RRM}$			50	μA
'R`	'R' current	T _j = 150 °C	VR - VRRM		100	1000	μΛ
V _E (2)	Forward voltage drop	T _j = 25 °C	I _F = 60 A			1.2	V
V _F ? Forward v	Torward voltage drop	T _j = 150 °C	IF = 00 A		0.83	1.0	V

- 1. Pulse test: $t_p = 5 \text{ ms}$, $\delta < 2\%$
- 2. Pulse test: $t_p = 380 \ \mu s$, $\delta < 2\%$

To evaluate the conduction losses use the following equation: P = $0.8 \times I_{F(AV)} + 0.0033 I_{F^2(RMS)}$

$$P = 0.8 \times I_{E(A)/2} + 0.0033 I_{E^2(PMS)}$$

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Table 5. Dynamic characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
t	Reverse recovery	T _i = 25 °C	$I_F = 1 \text{ A, } dI_F/dt = 50 \text{ A/}\mu\text{s}$ $V_R = 30 \text{ V}$		66	90	ns
t _{rr} time	time	1 _j = 25 °C	$I_F = 1 \text{ A, } dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 30 \text{ V}$		36	50	115
I _{RM}	Reverse recovery current	T _j = 125 °C	$I_F = 60 \text{ A}, V_R = 200 \text{ V}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$			15	А
S _{factor}	Softness factor	T _j = 125 °C	$I_F = 60 \text{ A}, V_R = 200 \text{ V}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$		0.4		
t _{fr}	Forward recovery time	T _j = 25 °C	$I_F = 60 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}$			600	ns
V _{FP}	Forward recovery voltage	T _j = 25 °C	$I_F = 60 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, \ V_{FR} = 1.1 \text{ x } V_{Fmax}$		3.2	70.	V

Figure 1. Conduction losses versus average forward current (per diode)

Figure 2. Forward voltage drop versus forward current (per diode)

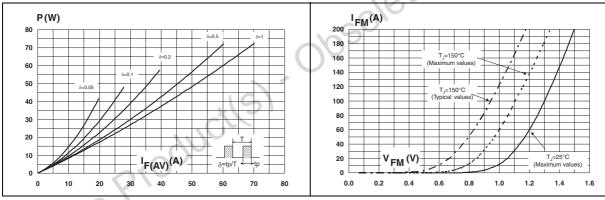
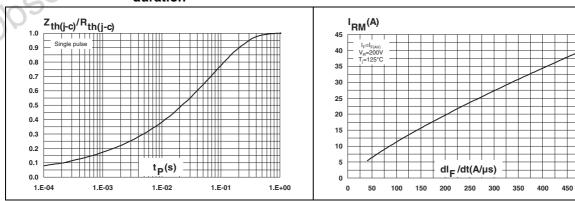


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

Figure 4. Peak reverse recovery current versus dI_F/dt (typical values, per diode)

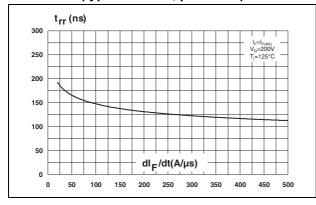


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Figure 5. Reverse recovery time versus dl_F/dt (typical values, per diode)

Figure 6. Reverse recovery charges versus dl_F/dt (typical values, per diode)



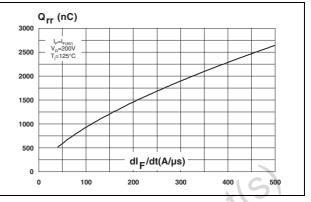
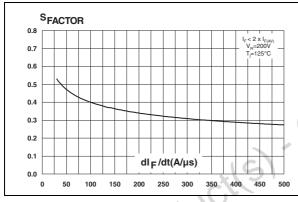
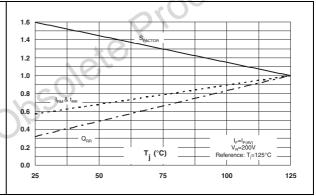


Figure 7. Reverse recovery softness factor versus dl_F/dt (typical values, per diode)

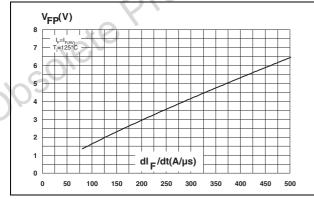
Figure 8. Relative variations of dynamic parameters versus junction temperature

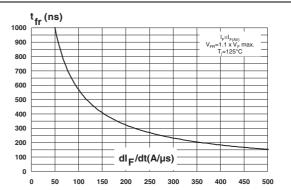




dl_F/dt (typical values, per diode)

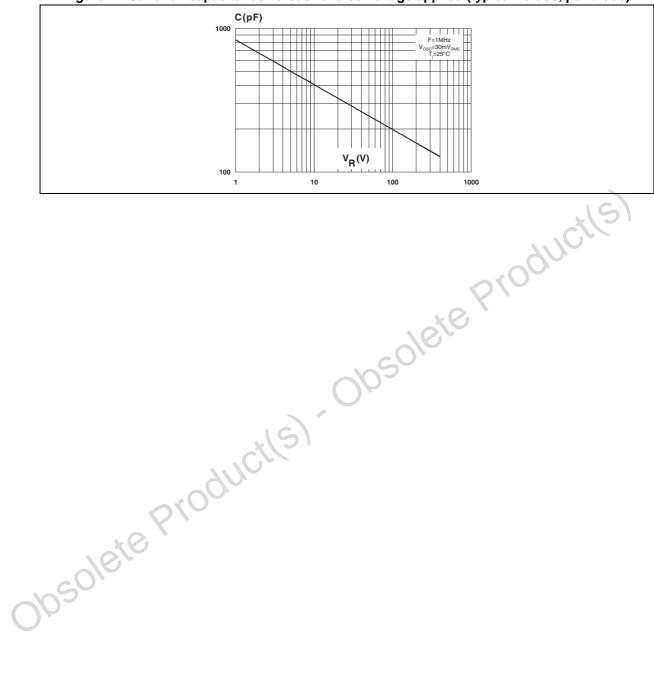
Figure 9. Transient peak forward voltage versus Figure 10. Forward recovery time versus dl_F/dt (typical values, per diode)





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Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)





Package information STTH60L04W

2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 to 1.0 N·m

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STTH60L04W Package information

Table 6. DO-247 dimension values

				Dimensio	ns			
	Ref.		Millimeters		Inches			
		Min.	Тур.	Max.	Min.	Тур.	Max.	
	А	4.85		5.15	0.191		0.203	
	D	2.20		2.60	0.086		0.102	
	Е	0.40		0.80	0.015		0.031	
	F	1.00		1.40	0.039		0.055	
	F2		2.00			0.078		
	F3	2.00		2.40	0.078		0.094	
	G		10.90			0.429		
	Н	15.45		15.75	0.608	10,0	0.620	
	L	19.85		20.15	0.781)	0.793	
	L1	3.70		4.30	0.145		0.169	
	L2		18.50	10		0.728		
	L3	14.20		14.80	0.559		0.582	
	L4		34.60	10 ₂		1.362		
	L5		5.50) "		0.216		
	М	2.00		3.00	0.078		0.118	
	V	X	5°			5°		
	V2	1,10	60°			60°		
	Dia.	3.55		3.65	0.139		0.143	
	O							
Note:	Leads and	slug are pure t	in plating finisl	hing				
Note:								

Ordering information STTH60L04W

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH60L04W	STTH60L04W	DO-247	4.4 g	30	Tube

4 Revision history

Table 8. Document revision history

	Date	Revision	Changes
	26-Oct-2006	1	First issue
	18-Mar-2013	2	Updated Package information on page 6.
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